

### **IN THE SPECIFICATION**

The specification was objected to for failing to provide proper antecedent basis. The objection stated that “claim 10 recites that ‘changing a thermodynamic condition includes changing both a pressure and temperature of the supercritical fluid,’ which apparently is not disclosed in the instant specification.” Please amend the specification as follows:

**The paragraph beginning at page 9, line 5 is amended as follows:**

Figure 4D shows the surface 404 of the semiconductor 400 and the remaining particle 412 within the feature 402 from Figure 4C. The atmosphere 422 within the chamber 420 is altered a second time to remove conditions within the chamber 420 from the supercritical state. Figure 4D shows a number of bubbles 424 forming at random locations within the carrier fluid 430. In one embodiment, after the supercritical conditions within the chamber 420 are removed, the supercritical fluid component of the homogenous fluid returns to a gas state, causing the bubbles 424 to form. One example of removing supercritical conditions within the chamber 420 includes reducing a temperature. Another example includes reducing a pressure. Another example includes reducing both a temperature and a pressure.

Applicant respectfully submits that the amended material was disclosed in the originally filed claims and thus was part of the specification already. No new matter is added pursuant to MPEP 608.01.